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Coherent control of electron spin dynamics in nano-engineered semiconductor structures

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Coherent Control
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Semiconductor Structures



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...to my parents and family

Contents

1	Introduction	1
1.1	Electron spin and polarization of light	2
1.2	Motivation	3
1.3	Outline of this thesis	11
2	Optical excitation and detection of electron spin coherence	15
2.1	Introduction	16
2.2	Optical transitions and selection rules	16
2.3	The Kerr effect	22
2.4	Balanced polarization bridge	25
2.5	Measurement setup	28
2.6	Measurement of the spin dephasing time (T_2^*)	31
2.7	Summary	33
3	Suppressed spin dephasing for 2D and bulk electrons in GaAs wires due to engineered cancellation of spin-orbit interaction terms	35
3.1	Introduction	36
3.2	Experimental realization	36
3.3	Signatures of spin dephasing anisotropy for 2DEG and bulk electrons	38
3.4	Summary of numerical simulations	43
3.5	Effect of external magnetic field on spin dephasing anisotropy . .	43
3.6	Effect of temperature and pump power on spin dephasing anisotropy	44
3.7	Conclusions	46
4	Spin-dephasing anisotropy for 2D electrons in a diffusive quasi-1D GaAs wire	49
4.1	Introduction	50
4.2	Method	52

4.3	Results and discussion	53
4.4	Conclusions	57
5	Spin-dephasing anisotropy for electrons in a quasi-1D GaAs wire without quantum confinement	59
5.1	Introduction	60
5.2	Spin-orbit coupling	61
5.3	Method	62
5.4	Results	64
5.5	Conclusions	70
6	Ultrafast mapping of optical polarization states onto spin coherence of localized electrons in a semiconductor	73
6.1	Introduction	74
6.2	Experimental realization of bijective mapping	75
6.3	Robustness of spin preparation	79
6.4	Repeated preparation of a spin state	81
6.5	Conclusions	82
7	Optical time-resolved study of the Landé g factor in n-doped GaAs materials	85
7.1	Introduction	86
7.2	Results	88
7.3	Conclusions	95
	Summary	99
	Samenvatting	101
	List of publications	103
	Curriculum vitae	105
	Acknowledgements	107